NSN 5962-01-368-3227

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View Online at https://aerobasegroup.com/nsn/5962-01-368-3227

Body Length:
Between 1.065 inches and 1.085 inches
Body Width:
Between 0.390 inches and 0.420 inches
Body Height:
Between 0.040 inches and 0.125 inches
Maximum Power Dissipation Rating:
500.0 milliwatts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
Features Provided:
W/disable and low current and 3-state output and high speed and hermetically sealed and high impedance
Inclosure Material:
Ceramic
Inclosure Configuration:
Dual-in-line
Output Logic Form:
Transistor-transistor logic
Input Circuit Pattern:
16 input
Current Rating Per Characteristic:
5.00 milliamperes reverse current, dc microamperes
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
-0.5 volts power source and 7.0 volts power source
Capitance Rating Per Characteristic:
7.50 input picofarads and 15.00 output picofarads
Time Rating Per Chacteristic:
350.00 nanoseconds access
Memory Device Type:
Ram
Terminal Type And Quantity:
22 printed circuit
Shelf Life:
N/a
Unit Of Measure:

Demilitarization: Yes - demil/mli

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